HD74LV245A

Octal Bus Transceivers with 3-state Outputs

HITACHI

ADE-205-247 (Z)

1st Edition
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Description

The HD74LV245A has eight buffers with three-state outputs in a 20-pin package. When DIR is high, data is transferred from the A inputs to the B outputs, and when DIR is low, data is transferred from the B inputs to the A outputs. The A and B buses are separated by making the enable input ($\overline{OE}$) high level. Low-voltage operation is suitable for battery-powered products (e.g., notebook computers), and the low power consumption extends the battery life.

Features

- V_{CC} = 2.0 V to 5.5 V operation
- All inputs V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V)
- All outputs V_O (Max.) = 5.5 V (@V_{CC} = 0 V)
- Typical V_{OL} ground bounce < 0.8 V (@V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.3 V (@V_{CC} = 3.3 V, Ta = 25°C)
- Output current ±8 mA (@V_{CC} = 3.0 V to 3.6 V), ±16 mA (@V_{CC} = 4.5 V to 5.5 V)

Function Table

Inputs

$\overline{OE}$	DIR	Operation
L	L	B data to A bus
L	H	A data to B bus
H	X	Isolation

Note: H: High level
L: Low level
X: Immaterial

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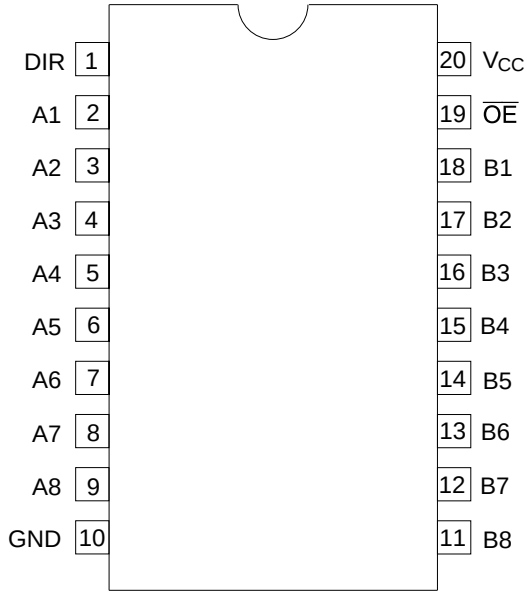
Pin Arrangement



(Top view)

Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V_{CC}	–0.5 to 7.0	V	
Input voltage range*[1]	V_I	–0.5 to 7.0	V	
Output voltage range*[1, 2]	V_O	–0.5 to V_{CC} + 0.5	V	Output: H or L
		–0.5 to 7.0		V_{CC}: OFF or Output: Z
Input clamp current	I_{IK}	–20	mA	$V_I < 0$
Output clamp current	I_{OK}	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	I_O	±35	mA	V_O = 0 to V_{CC}
Continuous current through V_{CC} or GND	I_{CC} or I_{GND}	±70	mA	
Maximum power dissipation at Ta = 25°C (in still air)*[3]	P_T	835	mW	SOP
		757		TSSOP
Storage temperature	Tstg	–65 to 150	°C	

Notes: The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time..

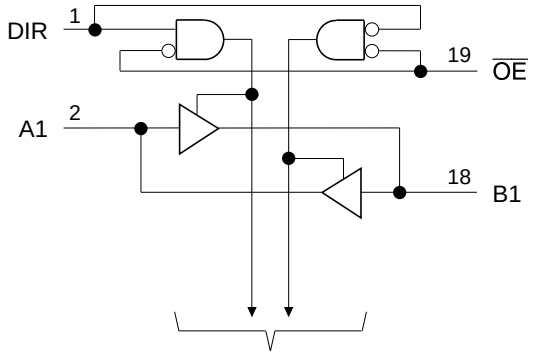
1. The input and output voltage ratings may be exceeded even if the input and output clamp-current ratings are observed.
2. This value is limited to 5.5 V maximum.
3. The data above are measured by ΔV_{BE} method mounting on glass epoxy board (40 × 40 × 1.6 mm) with 10% of wiring density.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V_{CC}	2.0	5.5	V	
Input voltage range	V_I	0	5.5	V	
Output voltage range	V_O	0	V_{CC}	V	Output: H or L
		0	5.5		High impedance state
Output current	I_{OH}	—	–50	μA	V_{CC} = 2.0 V
		—	–2	mA	V_{CC} = 2.3 to 2.7 V
		—	–8		V_{CC} = 3.0 to 3.6 V
		—	–16		V_{CC} = 4.5 to 5.5 V
	I_{OL}	—	50	μA	V_{CC} = 2.0 V
		—	2	mA	V_{CC} = 2.3 to 2.7 V
		—	8		V_{CC} = 3.0 to 3.6 V
		—	16		V_{CC} = 4.5 to 5.5 V
Input transition rise or fall rate	Δt /Δv	0	200	ns/V	V_{CC} = 2.3 to 2.7 V
		0	100		V_{CC} = 3.0 to 3.6 V
		0	20		V_{CC} = 4.5 to 5.5 V
Operating free-air temperature	Ta	–40	85	°C	

Note: Unused or floating inputs must be held high or low.

Logic Diagram



DC Electrical Characteristics

Ta = –40 to 85°C

Item	Symbol	V_{CC} (V)*[1]	Min	Typ	Max	Unit	Test Conditions
Input voltage	V_{IH}	2.0	1.5	—	—	V	
		2.3 to 2.7	$V_{CC} \times 0.7$	—	—		
		3.0 to 3.6	$V_{CC} \times 0.7$	—	—		
		4.5 to 5.5	$V_{CC} \times 0.7$	—	—		
	V_{IL}	2.0	—	—	0.5		
		2.3 to 2.7	—	—	$V_{CC} \times 0.3$		
		3.0 to 3.6	—	—	$V_{CC} \times 0.3$		
		4.5 to 5.5	—	—	$V_{CC} \times 0.3$		
Output voltage	V_{OH}	Min to Max	V_{CC} –0.1	—	—	V	I_{OH} = –50 µA
		2.3	2.0	—	—		I_{OH} = –2 mA
		3.0	2.48	—	—		I_{OH} = –8 mA
		4.5	3.8	—	—		I_{OH} = –16 mA
	V_{OL}	Min to Max	—	—	0.1		I_{OL} = 50 µA
		2.3	—	—	0.4		I_{OL} = 2 mA
		3.0	—	—	0.44		I_{OL} = 8 mA
		4.5	—	—	0.55		I_{OL} = 16 mA
Input current	I_{IN}	0 to 5.5	—	—	±1	µA	V_{IN} = 5.5 V or GND
Off-state output current	I_{OZ}*[2]	5.5	—	—	±5	µA	$V_O = V_{CC}$ or GND
Quiescent supply current	I_{CC}	5.5	—	—	20	µA	$V_{IN} = V_{CC}$ or GND, I_O = 0
Output leakage current	I_{OFF}	0	—	—	5	µA	V_O = 5.5 V
Input capacitance	C_{IN}	3.3	—	3.0	—	pF	$V_I = V_{CC}$ or GND
Output capacitance	C_O	3.3	—	5.5	—	pF	$V_O = V_{CC}$ or GND

Notes: 1. For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

2. For I/O ports, the parameter I_{OZ} includes the input leakage current.

Switching Characteristics

V_{CC} = 2.5 ± 0.2 V

		Ta = 25°C			Ta = –40 to 85°C					
Item	**Symbol**	**Min**	**Typ**	**Max**	**Min**	**Max**	**Unit**	**Test Conditions**	**FROM (Input)**	**TO (Output)**
Propagation delay time	t_{PLH} t_{PHL}	—	8.3	13.0	1.0	15.0	ns	C_L = 15 pF	A or B	B or A
		—	11.2	15.9	1.0	18.0		C_L = 50 pF		
Enable time	t_{ZH} t_{ZL}	—	11.8	19.9	1.0	22.0	ns	C_L = 15 pF	OE	A or B
		—	14.1	22.7	1.0	26.0		C_L = 50 pF		
Disable time	t_{HZ} t_{LZ}	—	11.8	18.1	1.0	20.0	ns	C_L = 15 pF	OE	A or B
		—	17.6	23.1	1.0	25.0		C_L = 50 pF		

V_{CC} = 3.3 ± 0.3 V

		Ta = 25°C			Ta = –40 to 85°C					
Item	**Symbol**	**Min**	**Typ**	**Max**	**Min**	**Max**	**Unit**	**Test Conditions**	**FROM (Input)**	**TO (Output)**
Propagation delay time	t_{PLH} t_{PHL}	—	5.9	8.4	1.0	10.0	ns	C_L = 15 pF	A or B	B or A
		—	7.9	11.9	1.0	13.5		C_L = 50 pF		
Enable time	t_{ZH} t_{ZL}	—	8.2	13.2	1.0	15.5	ns	C_L = 15 pF	OE	A or B
		—	9.9	16.7	1.0	19.0		C_L = 50 pF		
Disable time	t_{HZ} t_{LZ}	—	9.6	16.5	1.0	19.5	ns	C_L = 15 pF	OE	A or B
		—	13.9	19.8	1.0	22.0		C_L = 50 pF		

Switching Characteristics (cont)

V_{CC} = 5.0 ± 0.5 V

		Ta = 25°C			Ta = –40 to 85°C					
Item	**Symbol**	**Min**	**Typ**	**Max**	**Min**	**Max**	**Unit**	**Test Conditions**	**FROM (Input)**	**TO (Output)**
Propagation delay time	t_{PLH} t_{PHL}	—	4.3	5.5	1.0	6.5	ns	C_L = 15 pF	A or B	B or A
		—	5.6	7.5	1.0	8.5		C_L = 50 pF		
Enable time	t_{ZH} t_{ZL}	—	5.7	8.5	1.0	10.0	ns	C_L = 15 pF	OE	A or B
		—	7.0	10.6	1.0	12.0		C_L = 50 pF		
Disable time	t_{HZ} t_{LZ}	—	7.8	12.8	1.0	14.2	ns	C_L = 15 pF	OE	A or B
		—	10.9	14.7	1.0	16.0		C_L = 50 pF		

Output-skew Characteristics

C_L = 50 pF

Item	Symbol	V_{CC} (V)	Ta = 25°C Min	Ta = 25°C Max	Ta = –40 to 85°C Min	Ta = –40 to 85°C Max	Unit
Output skew	$t_{sk\ (O)}$	2.3 to 2.7	—	2.0	—	2.0	ns
		3.0 to 3.6	—	1.5	—	1.5	
		4.5 to 5.5	—	1.0	—	1.0	

Note: Skew between any outputs of the me package switching in the same direction. This parameter is warranted but not production tested.

Operating Characteristics

C_L = 50 pF

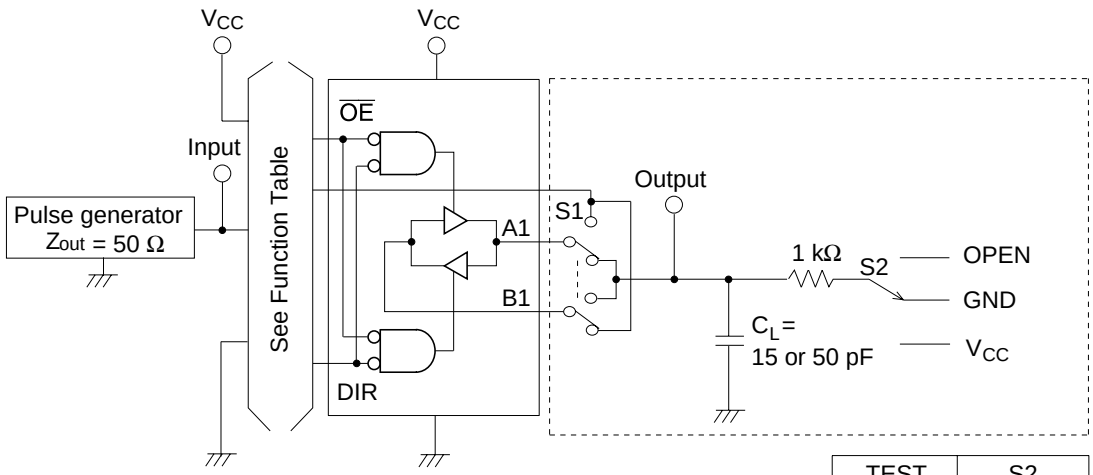
Item	Symbol	V_{CC} (V)	Ta = 25°C Min	Ta = 25°C Typ	Ta = 25°C Max	Unit	Test Conditions
Power dissipation capacitance	C_{PD}	3.3	—	20.0	—	pF	f = 10 MHz
		5.0	—	25.0	—		

Noise Characteristics

C_L = 50 pF

Item	Symbol	V_{CC} (V)	Ta = 25°C Min	Ta = 25°C Typ	Ta = 25°C Max	Unit	Test Conditions
Quiet output, maximum dynamic V_{OL}	$V_{OL\ (P)}$	3.3	—	0.5	0.8	V	
Quiet output, minimum dynamic V_{OL}	$V_{OL\ (V)}$	3.3	—	–0.4	–0.8		
Quiet output, minimum dynamic V_{OH}	$V_{OH\ (V)}$	3.3	—	2.9	—		
High-level dynamic input voltage	$V_{IH\ (D)}$	3.3	2.31	—	—	V	
Low level dynamic inout voltage	$V_{IL\ (D)}$	3.3	—	—	0.99		

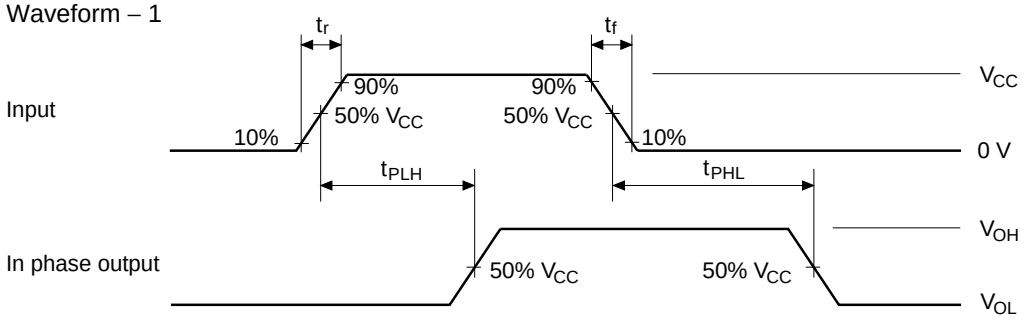
Test Circuit



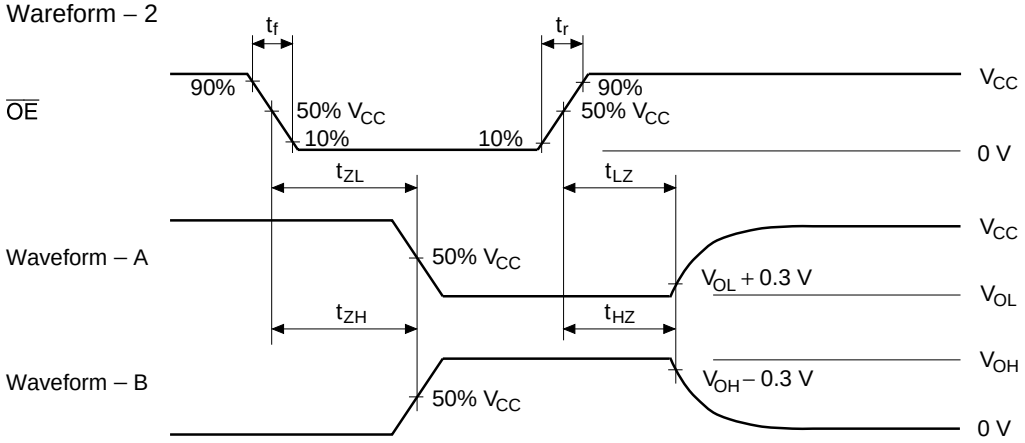
TEST	S2
t_{PLH}/t_{PHL}	OPEN
t_{ZH}/t_{HZ}	GND
t_{ZL}/t_{LZ}	V_{CC}

Notes : 1. C_L includes the probe and jig capacitance.
2. A2–B2 to A8–B8 are idential to above load circuit.
3. S1 : Input–Output change switch.

• Waveform – 1



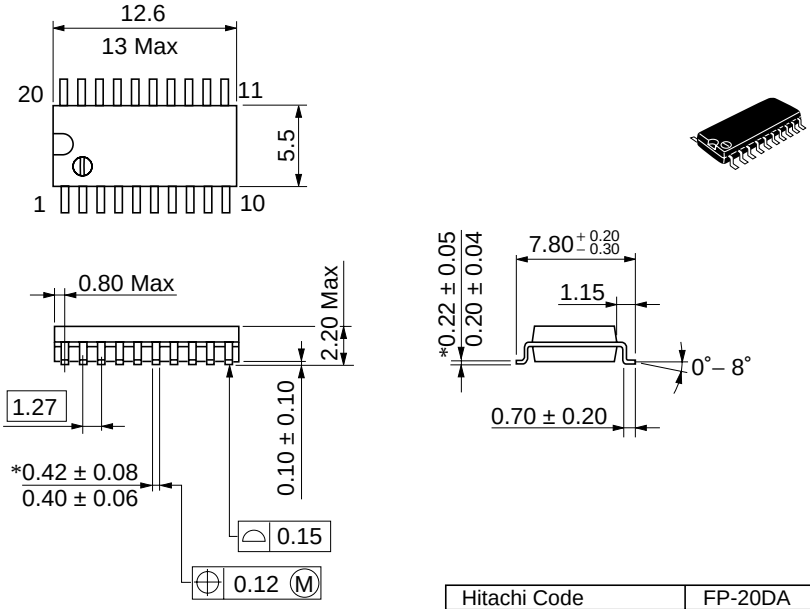
• Wareform – 2



Notes: 1. Input waveform: PRR ≤ 1 MHz, Zo = 50 Ω, t_r ≤ 3 ns, t_f ≤ 3 ns
2. Waveform–A is for an output with internal conditions such that the output is low except when disabled by the output control.
3. Waveform–B is for an output with internal conditions such that the output is high except when disabled by the output control.
4. The output are measured one at a time with one transition per measurement.

Package Dimensions

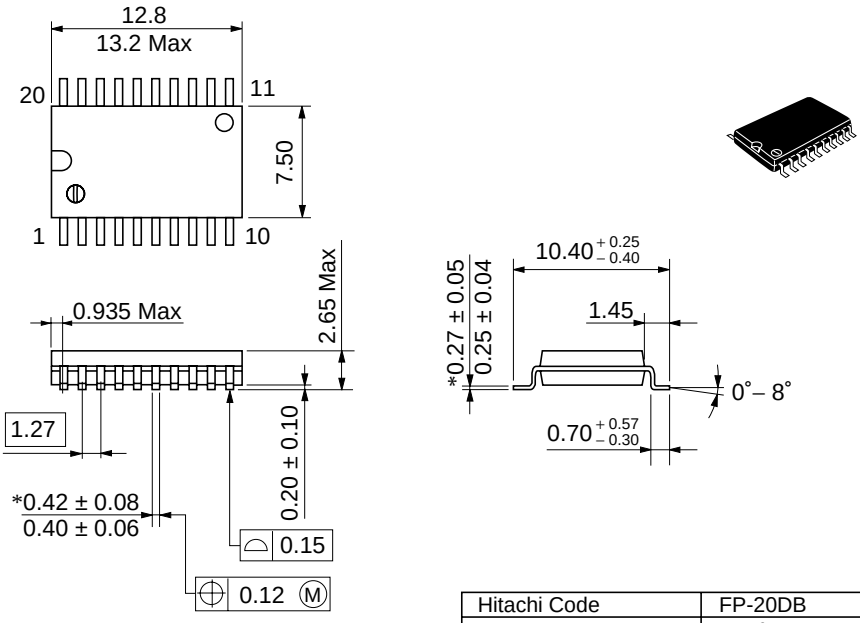
Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-20DA
JEDEC	–
EIAJ	Conforms
Weight (reference value)	0.31 g

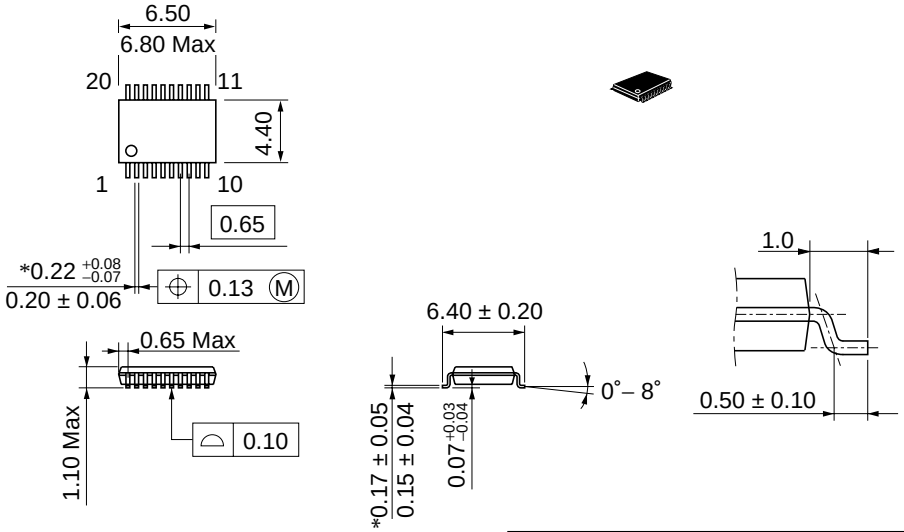
Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-20DB
JEDEC	Conforms
EIAJ	–
Weight (reference value)	0.52 g

Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	TTP-20DA
JEDEC	–
EIAJ	–
Weight (reference value)	0.07 g

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